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March 2015



FGH40N60SFD 600 V, 40 A Field Stop IGBT

Features

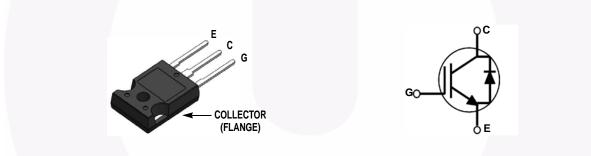
- High Current Capability
- Low Saturation Voltage: V_{CE(sat)} = 2.3 V @ I_C = 40 A
- High Input Impedance
- Fast Switching
- RoHS Compliant

Applications

 Solar Inverter, UPS, Welder, PFC, Microwave Oven, Telecom, ESS

General Description

Using novel field stop IGBT technology, Fairchild's field stop IGBTs offer the optimum performance for solar inverter, UPS, welder, microwave oven, telecom, ESS and PFC applications where low conduction and switching losses are essential.



Absolute Maximum Ratings

Symbol	Description		Ratings	Unit	
V _{CES}	Collector to Emitter Voltage		600	V	
V	Gate to Emitter Voltage	±20	V		
V _{GES}	Transient Gate-to-Emitter Voltage	±30	V		
I _C	Collector Current	@ T _C = 25°C	80	A	
	Collector Current	@ T _C = 100 ^o C	40	А	
I _{CM (1)}	Pulsed Collector Current	@ T _C = 25°C	120	А	
P _D	Maximum Power Dissipation	@ T _C = 25°C	290	W	
	Maximum Power Dissipation	@ T _C = 100 ^o C	116	W	
TJ	Operating Junction Temperature		-55 to +150	°C	
T _{stg}	Storage Temperature Range		-55 to +150	°C	
Τ _L	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C	

Notes:

1: Repetitive rating: Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Symbol Parameter		Max.	Unit	
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction to Case	-	0.43	°C/W	
$R_{\theta JC}$ (Diode)	Thermal Resistance, Junction to Case	-	1.45	°C/W	
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	-	40	°C/W	

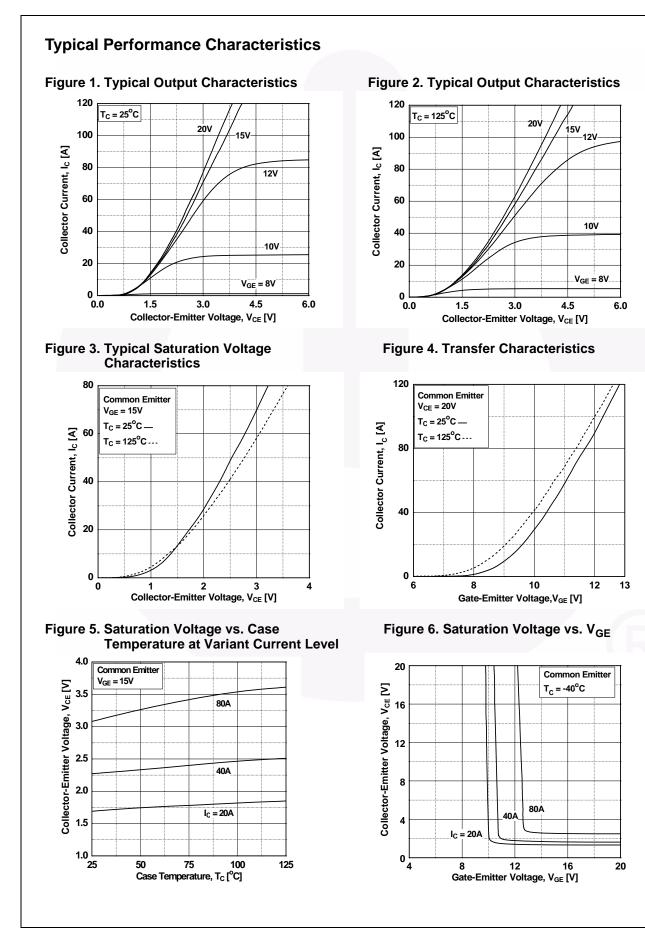
		Top Mark	Packa	ge Packing N	Packing Method	Reel Size		Tape Width		Quantity	
		TO-24	47 Tube		N/A	N/A		30			
Electric	al Cha	racteristics o	f the IC	GB.	T $T_{C} = 25^{\circ}C$ unless otherwise	e noted					
Symbol		Parameter			Test Conditions		Min.	Тур.	Max	. Unit	
Off Charac	teristics						-				
BV _{CES}	Collector	to Emitter Breakdowr	Voltage	Ver	_Ξ = 0 V, I _C = 250 μA		600	-	-	V	
ΔBV_{CES} / ΔT_J		ture Coefficient of Bre	0		_E = 0 V, I _C = 250 μA		-	0.6	-	V/ºC	
ICES		r Cut-Off Current		V _{CE} = V _{CES} , V _{GE} = 0 V		-	_	250	μA		
I _{GES}	G-E Lea	kage Current			$V_{GE} = V_{GES}, V_{CE} = 0 V$		-	-	±400		
510				01							
On Charac	teristics										
V _{GE(th)}	G-E Thre	eshold Voltage		-	= 250 μ A, V _{CE} = V _{GE}		4.0	5.0	6.5	V	
	Callester	llector to Emitter Saturation Voltage		-	= 40 A, V _{GE} = 15 V		-	2.3	2.9	V	
V _{CE(sat)}	Collector			I _C =	= 40 A, V _{GE} = 15 V, = 125 ^o C		-	2.5	-	V	
Dynamic C	haracteri	stics									
C _{ies}	Input Ca	pacitance					-	2110	-	pF	
C _{oes}	Output C	apacitance			$= 30 V, V_{GE} = 0 V,$		-	200	-	pF	
C _{res}	Reverse	Transfer Capacitance	•	f = 1 MHz		-	60	-	pF		
Switching	Character	ristics									
t _{d(on)}	Turn-On	Delay Time					-	25	-	ns	
t _r	Rise Tim	e					-	42	-	ns	
t _{d(off)}	Turn-Off	Delay Time		Vcc	_C = 400 V, I _C = 40 A,		-	115	-	ns	
t _f	Fall Time	e		R_{G}	= 10 Ω, V _{GE} = 15 V,		-	27	54	ns	
Eon	Turn-On	Switching Loss		Ind	uctive Load, $T_C = 25^{\circ}C$		-	1.13	-	mJ	
E _{off}	Turn-Off	Switching Loss					-	0.31	-	mJ	
E _{ts}	Total Sw	itching Loss					-	1.44	-	mJ	
t _{d(on)}	Turn-On	Delay Time					-	24	-	ns	
t _r	Rise Tim	e					-	43	-	ns	
t _{d(off)}	Turn-Off	Delay Time		V_{CC} = 400 V, I _C = 40 A, R _G = 10 Ω, V _{GE} = 15 V,			-	120	-	ns	
t _f	Fall Time	9					-	30	-	ns	
Eon	Turn-On	Switching Loss		Ind	uctive Load, T _C = 125 ^o C	,	-	1.14	-	mJ	
E _{off}	Turn-Off	Switching Loss		1			-	0.48	-	mJ	
E _{ts}	Total Sw	itching Loss		Ī			-	1.62	-	mJ	
Qg	Total Gat	te Charge					-	120	-	nC	
Q _{ge}	Gate to E	Emitter Charge			= 400 V, I _C = 40 A,		-	14	-	nC	
Q _{gc}	Coto to (Collector Charge	V		V _{GE} = 15 V		_	58	-	nC	

FGH40N
60SFD —
600 V, 40
) A Field
Stop IGB

Symbol	Parameter	Test Condition	Min.	Тур.	Max	Unit	
V_{FM}	Diode Forward Voltage	I _E = 20 A	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	1.95	2.6	V
		1F - 20 M	$T_{\rm C} = 125^{\rm o}{\rm C}$	-	1.85	-	
t _{rr}	Diode Reverse Recovery Time		$T_{\rm C} = 25^{\rm o}{\rm C}$	-	45	-	ns
		I _F =20 A, di _F /dt = 200 A/μs	$T_{\rm C} = 125^{\rm o}{\rm C}$	-	140	-	
Q _{rr}	Diode Reverse Recovery Charge	$r_{\rm F} = 20 \text{ A}, \ \text{ar}_{\rm F}/\text{at} = 200 \text{ A}/\mu\text{s}$	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	75	-	nC
			$T_{\rm C} = 125^{\rm o}{\rm C}$	-	375	-	

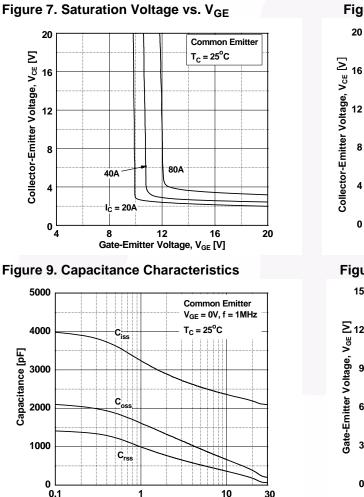
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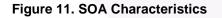
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Typical Performance Characteristics

Collector-Emitter Voltage, V_{CE} [V]

1



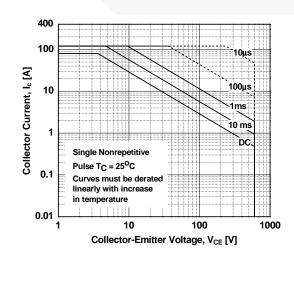
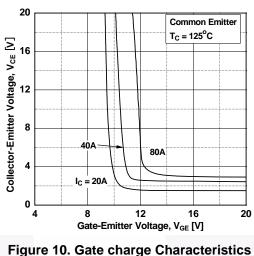
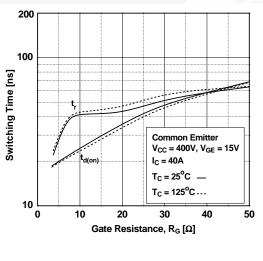


Figure 8. Saturation Voltage vs. V_{GE}



Common Emitter $T_C = 25^{\circ}C$ Gate-Emitter Voltage, V_{GE} [V] 8 0 6 71 200V = 100V 300V 0 50 100 150 0 Gate Charge, Q_q [nC]

Figure 12. Turn-on Characteristics vs. **Gate Resistance**

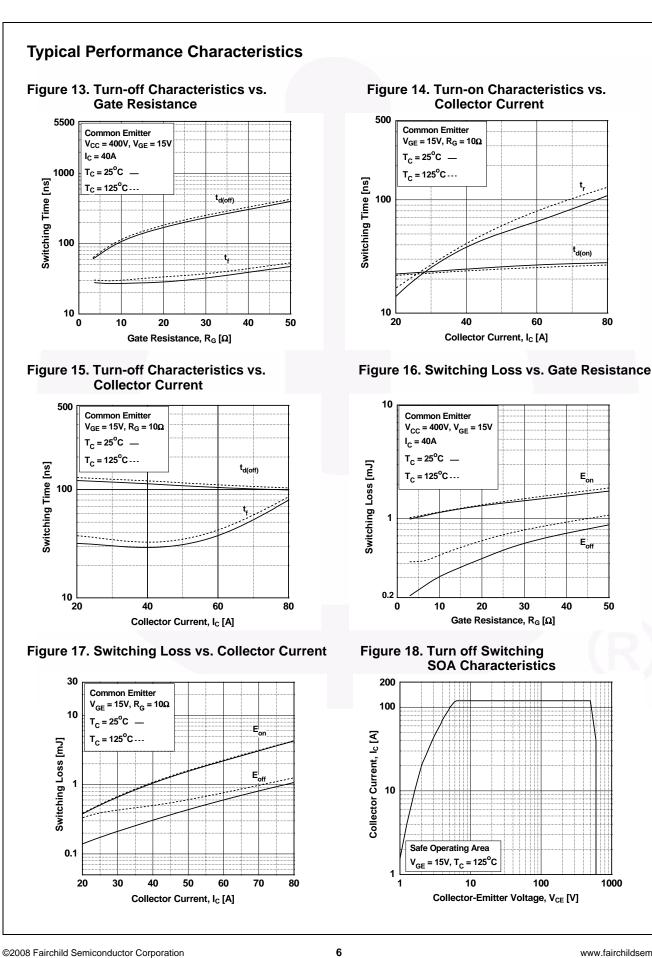


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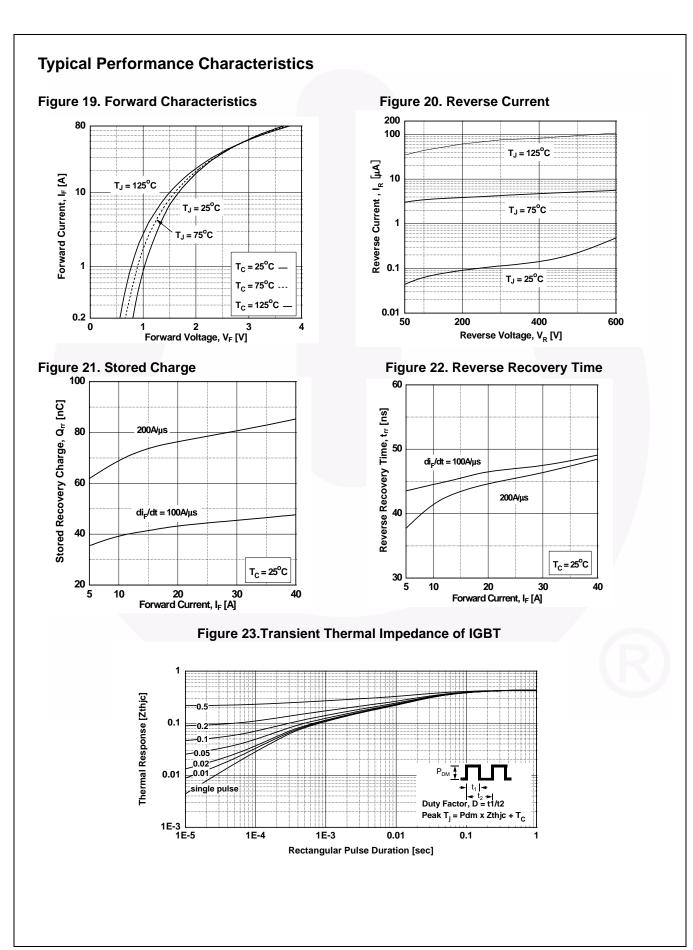
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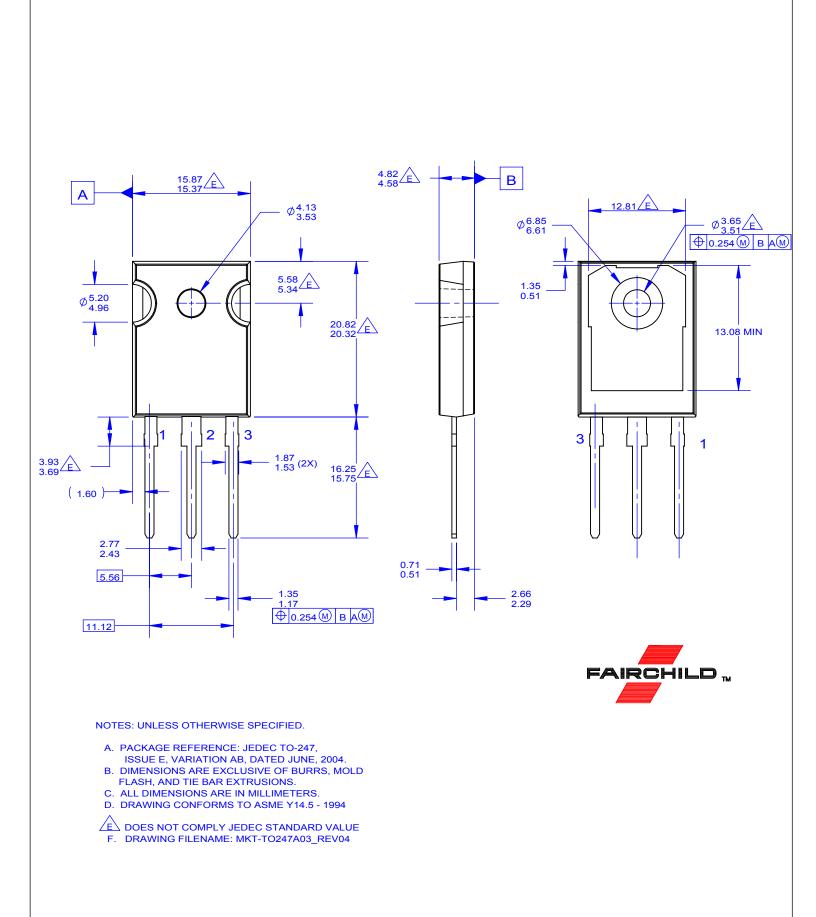
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